NSN 5961-01-175-2582

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-175-2582 **Inclosure Material:** Metal **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak off-state voltage and 800.0 repetitive peak reverse voltage and 960.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 63.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 2.0 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No